

$^{114}\text{Sn}(\text{p},\text{p}'\gamma)$ 1976Ba32

Type	Author	History Citation	Literature Cutoff Date
Full Evaluation	Jean Blachot	NDS 113, 515 (2012)	1-Jan-2012

E=6.4,6.92 MeV.

Only low-lying states excited via the s1/2 IAR in ^{114}Sn .

Measured electrons (magnetic lens + Si(Li)).

 ^{114}Sn Levels

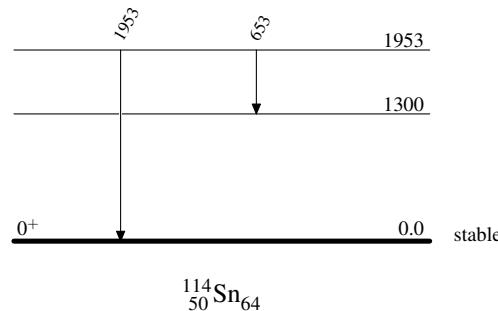
$E(\text{level})^\dagger$	J^π	$T_{1/2}$
0.0	0^+	stable
1300		
1953		

† Rounded-off values from Adopted Levels.

 $\gamma(^{114}\text{Sn})$

E_γ^\dagger	$E_i(\text{level})$	E_f	J_f^π	Comments
653	1953	1300		I_γ : Ice(K)(1953 γ)/Ice(K)(653 γ)=1.00 20.
1953	1953	0.0	0^+	

† Rounded-off values from Adopted Levels.

 $^{114}\text{Sn}(\text{p},\text{p}'\gamma)$ 1976Ba32Level Scheme $^{114}_{50}\text{Sn}_{64}$